Transistor





Description:



A Silicon NPN transistor in a TO-39 case intended for high speed switching applications.

Absolute Maximum Ratings:

Collector-Emitter Voltage, VCEO : 40V Collector-Base Voltage, VCBO : 75V Emitter-Base Voltage, VEBO : 6V Continuous Collector Current, Ic : 800mA Total Device Dissipation (T_A = +25°C), P_D : 400mW Derate above 25°C : 2.28mW/°C Total Device Dissipation (Tc = + 25°C), PD : 1.2W Derate above 25°C : 6.85mW/°C Operating Junction Temperature Range, TJ: -65°C to +200°C : -65°C to 200°C Storage Temperature Range, Tstg

Electrical Characteristics: (T_A = +25°C Unless otherwise specified

Parameter	Symbol	Test Conditions	Min	Max	Unit
OFF Characteristics			'		
Collector-Emitter Breakdown Voltage	V(BR)CEO	Ic = 10mA, I _B = 0	40	-	V
Collector-Base Breakdown Voltage	V(BR)CBO	Ic = 10μA, Iε = 0	75	-	V
Emitter-Base Breakdown Voltage	V(BR)EBO	IE = 10μA, Ic = 0	6	-	V
Collector Cut-Off Current	Ісво	Vce = 60V, Ie = 0	-	0.01	μΑ
		VCE = 60V, IE = 0, TA = +150°C	-	10	μΑ
	ICEX	VCE = 60V, VEB(off) = 3V	-	10	μΑ
Emitter Cut-Off Current	VEB = 3V, Ic = 0	-	10	μΑ	
Base Cut-Off Current	İBL	VCE = 60V, VEB(off) = 3V	-	20	μΑ
On Characteristics					
DC Curent Gain	hFE	Ic = 0.1mA, VcE = 10V	20	-	-
		Ic = 1mA, VcE = 10V	50	-	-
		Ic = 10mA, VcE = 10V	75	-	-
		Ic = 10mA, VcE = 10V, TA = -55°C	35	-	-
		Ic = 150mA, VcE = 10V	100	300	-
		Ic = 150mA, VcE = 1V		-	-
		Ic = 500mA, VcE = 10V		-	-
Collector-Emitter Saturation Voltage	VCE(sat)	Ic = 150mA, I _B = 5mA	-	0.3	V
(Note 1)		Ic = 500mA, I _B = 50mA		1	V
Base-Emitter Saturation Voltage	VBE(sat)	Ic = 150mA, I _B = 15mA	0.6	1.2	V
(Note 1)		Ic = 500mA, I _B = 50mA	-	2	V

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Small-Signal Characteristics

Current Gain-Bandwidth Product (Note 2)	fτ	Ic = 20mA, VcE = 20V, f = 100MHz, (Note 2)	300	-	MHz
Output Capacitance	Cobo	Vcb = 10V, IE = 0, f = 100kHz	-	8	pF
Input Capacitance	Cibo	VEB = 0.5V, Ic = 0, f = 100kHz	-	25	pF
Input Impedance	h	Ic = 1mA, Vce = 10V, f = 1kHz	2	8	kΩ
Input Impedance	h _{ie}	Ic = 10mA, Vce = 10V, f = 1kHz	0.25	1.25	kΩ
Voltage Foodback Datio	Hre	Ic = 1mA, VcE = 10V, f = 1kHz		8	×10 ⁻⁴
Voltage Feedback Ratio		Ic = 10mA, Vce = 10V, f = 1kHz	-	4	×10 ⁻⁴
Output Admittance	hoe	Ic = 1mA, Vce = 10V, f = 1kHz	5	35	µmhos
Output Admittance	Noe	Ic = 10mA, VcE = 10V, f = 1kHz	25	200	μmhos
Collector-Base Time Constant	rb′Cc	Ic = 20mA, VcB = 20V, f = 31.8mHz	5	150	ps
Noise Figure	NF	Ic = 100μA, Vcε = 10V, Rs = 1κΩ, f = 1kMHz	-	4	dB
Real Part of Common-Emitter High Frequency input Impedance	Re(h _{ie)}	Ic = 20mA, Vce = 20V, f = 300MHz	-	60	Ω

Switching Characteristics

Delay Time	t _q	Vcc = 30V, Ic = 150mA, V _{BE(off)} = 0.5V, I _{B1} = 15mA		10	ns
Rise Time	tr			25	ns
Storage Time	ts	Vcc = 30V, Ic = 150mA, I _{B1} = I _{B2} = 15mA	-	225	ns
Fall Time t _f		Vec - 30V, 1c - 130111A, 1B1 - 1B2 - 13111A		60	ns
Active Region Time Constant	TA	Ic = 150mA, VcE = 30V	-	2.5	ns

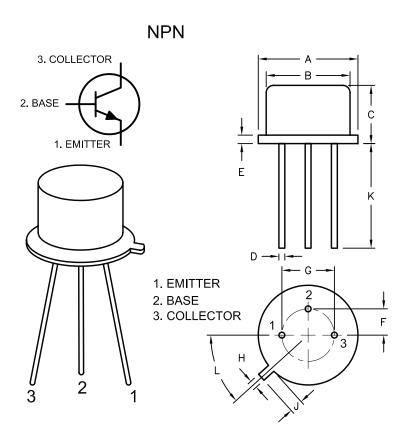
Notes

- 1. Pulse Test: Pulse Width ≦ 300µs, Duty Cycle ≦ 2%.
- 2. ft is defined as the frequency at which $|\mathbf{h}_{\text{fe}}|$ extrapolates to unity.



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Dimensions	Α	В	C	D	Е	F	G	H	7	K	L
Min.	8.5	7.74	6.09	0.4	1	2.41	4.82	0.71	0.73	12.7	42°
Max.	9.39	8.5	6.6	0.53	0.88	2.66	5.33	0.86	1.02	-	48°

Dimensions: Millimetres

Part Number Table

Description	Part Number		
Bipolar, TO-39, NPN, Silicon, High Speed Switching	2N2219A		

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